SAMPLE CONTENT

Challenger

CHENISTRY Vol - II Now with more study NEET-UG & JEE (Main)

2080 MCQs with Hints

For all Agricultural, Medical, Pharmacy and Engineering Entrance Examinations held across India.

Transition metals

Transition metals form coloured compounds and are widely used to make coloured glasses.

f. Santosh Yadav M. Sc., SET, NET Prof. Anil Thomas M.Sc., Chemistry

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Challenger NEET – UG & JEE (Main) Chemistry vol. II

Now with more study techniques

Salient Features

- Concise theory for every topic.
- Eclectic coverage of MCQs under e h sub-topic
- 2080' questions including MCQs fron vevice NEET and JEE examinations.
- Includes selective solved MCQs upto NEET Phase-I & II 2020, JEE (Main) 2020.
- Includes NEET Phase-II J20 ad JEE (Main) 2020 2nd September (Shift II)
 Question Paper an. Answer U cy a ong with Hints.
- Multiple Study Tech. ues Er ance Understanding and Problem Solving.
- Hints provided ver remed necessary.
- Includes Nu. rical Vi ue Type Questions (NVT).
- Inclusion f'Pt lem To Ponder' to engage students in scientific enquiry.

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PREFACE

'Challenger Chemistry Vol - II' is a compact guidebook, extremely handy for preparation of various competitive exams like NEET, JEE (Main). This edition provides an unmatched comprehensive amalgamation of theory with MCQs. The chapters are aligned with the syllabus for NEET (UG) and JEE (MAIN) examinations and runs parallel to NCERT curriculum. The book provides the students with scientifically accurate context, several study techniques and skills required to excel in these examination

Each chapter in the book consists of:

- **Consice theory** covering concepts that form a vital part of preparation any competitive exarting in the form of pointers, tables, charts and diagrams.
- **Concept Building Problems** section is designed to boost prerequisite understanding of conc. 's.
- **Practice Problems** section contains questions crafted for thorough revision.
- **Diagram Based Problems** section contains questions that facilitates stucts' conceptual understanding and enhance their spatial thinking ability.
- Numerical Value Type section cater to newly added NVT questions *JEL* Main,
- **Problems to Ponder** section offers MCQs of diverse pattern c₁ ted to 1.still the attitude of concentrating on the problems and to understand the application variation concepts in Chemistry.

All the questions included in a chapter have been specially creat 1 and co piled to enable students solve complex problems which require strenuous effort with some tress.

All the features of this book pave the path of a stue ent to excel be examination. The features are designed hagement, the following elements in mind: Time n agement, the symemorization or revision and non-conventional yet simple methods for MCQ solving.

To keep students updated, selected questions from most recuit examinations of NEET (UG) 2020 and JEE (Main) 2020 are covered exclusively.

NEET-UG 2020 (Phase II) and JFE (Ma⁺) 20° , 2^{nd} SEPTEMBER (Shift – II) Question Papers and Answer Keys have been provided to othe studies of the complexity of questions asked in entrance examination. The paper has been $s_{\rm F}$, it units to let the students know which of the units were more relevant in the latest examination.

We hope the book benefits t^{k-1} earner ι , we have envisioned.

A book affects eternit[,] reca. rever ell where its influence stops.

From, Publisher

Edition: Fourth

The jurner a preate a complete book is strewn with triumphs, failures and near misses. If you think we've yearly milled s mething or want to applaud us for our triumphs, we'd love to hear from you.

Please w. . . us on: mail@targetpublications.org

Disclaimer

This reference book is based on the NEET-UG and JEE (Main) syllabus prescribed by National Testing Agency (NTA). We the publishers are making this reference book which constitutes as fair use of textual contents which are transformed by adding and elaborating, with a view to simplify the same to enable the students to understand, memorize and reproduce the same in examinations.

This work is purely inspired upon the course work as prescribed by the National Council of Educational Research and Training (NCERT). Every care has been taken in the publication of this reference book by the Authors while creating the contents. The Authors and the Publishers shall not be responsible for any loss or damages caused to any person on account of errors or omissions which might have crept in or disagreement of any third party on the point of view expressed in the reference book.

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FEATURES

5.

5.

5.



'Strategy' illustrates a general step-by-step approach towards solving a problem.

This is our attempt to guide students to map out a strategy for solving the problem.

The vapour pressure of acetone at 20 °C is 185 torr. When 1.2 g of a non-volatile substance was dissolved in 100 g of acetone at 20 °C, its vapour pressure was 183 torr. The molar mass $(g \text{ mol}^{-1})$ of the substance : [JEE (Main) 20 5] 32 (A) (B) 64 128 (C) (D) 488 (B) Strategy Binary solution containing non-volatile, non-electrolyte ¹ute p_A^o , p_A , W_B and W_A I e formula. p_A^o – $W_{\rm B} \times N$ $p_{\rm A}^{\rm o}$ M. . Molar m s of solute (M_B) $\frac{p_{A}^{\circ} - p_{A}}{p_{A}^{\circ}} = \frac{W_{B}M_{A}}{M_{B}W_{A}}$ $\frac{18}{_{1}85} - \frac{183}{_{1}85} = \frac{1.2 \times 58}{M_{_{\rm B}} \times 100}$ $M_{\rm B} = \frac{1.2}{2} \times \frac{58}{100} \times 185 = 64.38 \approx 64 \text{ g/mol}$



FEATURES

Caution

'Caution' apprises students about mistakes which are made while solving an MCQs. *This is our attempt to make a student aware of possible common mistakes.*

CAUTION

Ensure to convert edge length from Å to cm before substituting in the density formula.

SMART CODE - 2

For 3d series: Sc, Ti, V, Cr, Mn, Fe, Co, Ni, Cu, Zn.
Scary Tiny Vicious Creature May Fear Cows and Nice Cute Zebras.
For 4d series: Y, Zr, Nb, Mo, Tc, Ru, Rh, Pd, Ag, Cd.
Yes, Zebras can Never, but Most Technicians can Road Rhymes Properly And Correctly.
For 5d series: La, Hf, Ta, W, Re, Os, Ir, Pt, Au, 1 g.

Late Harry Took a Walk and Reached Office In Pajamas After an Hour.

Smart Inde

This is c * atte.npt to offer students a memory echnique that facilitates v rec .lection.

Q.R. Codes

'Q.R. code' provides access to a video in order to boost under andme of a concept or activity. This is our attempt to juilitate learning with visue and Students can scan the adjacent QR code to *ret further conceptual clarity on seven* crystal systems.



⊏orm⊾ ∵e

2.

.ke, **•tion potential** = – Oxidation Potential

 $\mathbf{F}^{\circ}_{\text{eff}} (\mathbf{e.m.f}) = \mathrm{E}^{\circ}_{(\text{cathode})} - \mathrm{E}^{\circ}_{(\text{anode})}$ $= \mathrm{E}^{\circ}_{(\text{Right})} - \mathrm{E}^{\circ}_{(\text{Left})}$

Gibbs energy change and e.m.f. of a cell:

 $\Delta_{\rm r}G = -nFE_{\rm cell}$ and $\Delta_{\rm r}G^{\circ} = -nFE_{\rm cell}^{\circ}$

Where, $\Delta_r G = Gibbs$ energy change $\Delta_r G^\circ = Standard Gibbs$ energy change

Formulae

Formulae' includes all of the key formulae in the chapter. *This is our attempt to offer students tools of formulae accessible while solving problems and last minute revision at a glance.*

FEATURES

A compound 'X' upon reaction with H_2O produces a colourless gas 'Y' with rotten fish smell. Gas 'Y' is absorbed in a solution of $CuSO_4$ to give Cu_3P_2 as one of the products. Predict the compound 'X'.

(A)	$Ca_3(PO_4)_2$	
$\dot{\mathbf{C}}$	NH _C 1	

3.

Ĥ

[NEET (Odisha) 2019] (B) Ca₃P₂ (D) As₂O₃

2.

Clock Symbol

Clock Symbol' instructs students that given MCQ can be solved apace by applying either smart tips, smar codes or thinking hatke.

This is our attempt to make students attentive towards their percepties i of approaches possible for sole j and MCQ.

Miscellaneous

Miscellaneous MCQs covers concept of different sub-topics of same chapter or from different chapters.

This is our attempt to develop cognitive thinking in the students essential to solve questions involving fusion of multiple key concepts.

MISCELLANEOUS

Phenol $\xrightarrow{a} X \xrightarrow{b}$ Toluer

- Identify reagents 'a' and 'b'
 - (A) a = NaOH b CO_2/H^+
 - (B) $a = CHCl_3/NaO^{II} b = 1 OH/H^+$
 - (C) $a = Zn dust_1$, $L Ch_2$ 'l, anhydrous AlCl₃
 - (D) $a = Na_2Cr_2(/H^+ b = \text{Caney Ni})$

0.44 mole of electrons were part 1 through four electrolyte solutions for 1 secon convited in series. If the solutions are c AlCl₃ Zr^c J_4 , uCl₃ and AgNO₃, find the CORRE T dec 4sing ℓ der of the amount of each metal depoined at indee of each cell. (M.W.: Al = 27 in 55.4, g = 108, Au = 197) (A) Ag > Au > 7 > Al(b) Al > Zn > Ag > Au (C) Au > Ag > ι > Al(D) Al > Zn > Au > Ag (A)

2.

2.

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2. According to Fail 'ay's wond law of electrolysis, mass related the field of quivalent weight

$$E_{eq}(^{3+}) = \frac{1}{3} = 9, E_{eq}(Ag^+) = \frac{108}{1} = 108$$

 $E_{e}(^{7}n^{27}), \frac{65.4}{2} = 32.7, E_{eq}(Au^+) = \frac{197}{3} = 65.6$

lenc the correct decreasing order of amount of diffe ent metals deposited is:

a > Au > Zn > Al

Thinking Hatke - Q.2

Since, same quantity of electricity is passed through all the electrolytes; mass of metal deposited in each case will be proportional to their respective equivalent weights. Equivalent weight of Ag is highest among these metals. Hence, option (A) is the correct answer.

Thinking Hatke

'Thinking Hatke' reveals quick witted approach to crack the specific question. This is our attempt to develop skill of lateral thinking in students.

Why Challenger Series?

Gradually, every year the nature of competitive entrance exams is inching towards conceptual understanding of topics. Moreover, it is time to bid adieu to the stereotypical approach of solving a problem using a single conventional method.

To be able to successfully crack the NEET/JEE (Main) examinations, it is imperative a develop skills such as data interpretation, appropriate time management, knowing various method to solve a problem, etc. With Challenger Series, we are sure, you'd develop all the aforementioned skills and take a more holistic approach towards problem solving. The way you'd tackle advectional level MCQs with the help of hints, Smart tips, Smart codes and Thinking Hatke would give ou the necessary practice that would be a game changer in your preparation for the competitive environment.

> What is the intention behind the launch of Challenger Series?

The sole objective behind the introduction of Challenger Series is to severity the the science is preparedness to take competitive entrance examinations. With an eclectic respective of critical and advanced level MCQs, we intend to test a student's MCQ solving states within the pulated time period.

What do I gain out of Challenger Series?

After using Challenger Series, students would be able to:

- a. assimilate the given data and apply relevant $correspondents \sqrt{1}$ th utmose ease.
- b. tackle MCQs of different pattern such is match the plum is, diagram based questions, multiple concepts and assertion-reason e iciently.
- c. garner the much needed confidence to appear for computitive exams.
- d. easy and time saving methods to tackle tracy questices will help ensure that time consuming questions do not occupy more time than you can be per question.

How to derive the best advantage ... 'ook?

f.

To get the maximum benefⁱ⁺ of the ook verecommend :

- a. Go through brief theo give a the eginning of a chapter for a quick revision. Commit Smart Tips into memory 1 pa, alon to Caution.
- b. Know all the Form ... romp rd at the end of theory by heart.
- c. Using subtopic v ise seq. gation as a leverage, complete the Concept Building Problems at your own pace. Destions from various competitive exams such as JEE (Main), NEET-UG, NEET (Concept) are the conds of questions in various exams.
- d. Be xtra eceptive to Lanking Hatke, Alternate Method and application of Smart Tips. A milate minto your thinking.
- e. Afte. mastering stimulating questions, take up Practice Problems as self-assessment and rify a rivers as well as methods. Check if you could apply smart tips, alternate method, etc. as mentioned in hint. Find out if you have invented ingenious solution mapping to this ring hatke explicated in hints.
 - atch the linked video for an efficient revision of chapter theory.
 - Ruminate over questions from Problems To Ponder and appreciate aesthetics of the concepts.

Can the Questions presented in Problems to Ponder section be a part of the NEET Examination? No, the questions would not appear as it is in the NEET Examination. However, there are fair chances that these questions could be covered in parts or with a novel question construction.

Best of luck to all the aspirants!



No.	Topic Name	Page No.
1	Solid state	1
2	Solution	3
3	Electrochemistry	د8
4	Chemical Kinetics	124
5	Surface Chemistry	1 5
6	General Principles and Processes of Isolation of Elements	204
7	p-Block Elements	239
8	d and f-Block Elements	310
9	Coordination Compounds	347
10	Haloalkanes and Haloarenes	386
11	Alcohols, Phenols and Ethers	447
12	Aldehydes, Ketones and Carboxylic Actua	512
13	Organic Compounds Contzinue Nitrogen	599
14	Biomolecules	659
15	Polymers	698
16	Chemistry in F /eryda, Life	726
17	Principle ⁻ ^P elat. ¹ to P letical Chemistry	749
	NEFT UG) 1. 'se-1. '020 Question Paper & Answer Key	801
	T 2 (Ma.) 2020 : Question Paper & Answer Key 2' `EPTEL BER (Shift – II)	804

INOL

* marked subtopic in a chapter is listed only in the JEE syllabus and ** marked subtopic in a chapter is listed only in the NEET syllabus. However, since questions based on the same have appeared in the recent examinations, these subtopics are covered judiciously in the book.

sample



Classificatio. f solids:

Set its b class field into the following two types on the basis of the presence or absence of orderly a angement of the constituent particles:

- **Crys** alline solids: A crystalline solid is a homogeneous solid in which the constituent particles, atoms, ions or m_{c} as are arranged in a definite repeating pattern in three dimensional space.
 - A orphous solids: The substances that appear like solids but do not have well developed perfectly ordered ar angement of constituent particles are called amorphous (no form) solids.

	Property Crystalline solids Amorphous solid		
a.	Shape	They have definite characteristic geometrical shape due to the orderly regular long range arrangement of constituent particles.	They have irregular shape i.e., lack characteristic geometrical shape due to the short ranged orderly arrangement of constituent particles.
b.	Melting point	They have sharp and characteristic melting point.	They do not have sharp melting point. They gradually soften over a range of temperature.



Students can scan the adjacent QR code to get further conceptual clarity on seven crystal systems.



6

b. The following table gives the limiting values of radius ratio, the coordination number of the cation and the structural arrangement of anions around cations.

Radius ratio $\frac{\mathbf{r}^{+}}{\mathbf{r}^{-}}$ Coordinationnumber of cation		Structural arrangement of anions around cations	Examples
0.155 to 0.225	3	Planar triangular	B ₂ O ₃
0.225 to 0.414	4	Tetrahedral	ZnS
0.414 to 0.732	6	Octahedral	NaCl
0.732 to 1.0 8		Cubic	CsCl

ii. Structures of some ionic solids:

	Ionic solid	Arrangement of ions	Coordina, n nu, ver
a.	NaCl (Sodium chloride)	$Cl^- \Rightarrow fcc arrangement$	1 =
		$Na^+ \Rightarrow$ occupy all octahedral sites	6
b.	CsCl (Caesium chloride)	$Cl^- \Rightarrow$ simple cubic arrangement	Cl
		$Cs^+ \Rightarrow$ occupy cubic sites	$r_{s}^{+} = 8$
c.	ZnS (Zinc blende)	$S^{2-} \Rightarrow$ fcc arrangement	S- = 4
		$Zn^{2+} \Rightarrow$ occupy half of the tetrahed 'sites	$Zn^{2+} = 4$
d.	CaF ₂ (Calcium fluoride)	$Ca^{2+} \Rightarrow fcc arrangement$	$Ca^{2+} = 8$
		$F^{-} \Rightarrow$ occupy all tetrahed f sites	$F^{-} = 4$

iii. Sizes of tetrahedral and octahedral voids:

Radius (r) of tetrahedral void = 0.225 R

Radius (r) of octahedral void = 0.414 R

R = radius of the spheres in the close packed a ngement.

1.8 PACKING EFFICIENCY

> Packing efficiency:

ii.

The packing efficiency is the recent re tota pace occupied by the particles.

Vo me of the unit cell

i. Packing efficiency is given by folloving formula:

Packing efficiency = $\frac{\text{Tot ivolum}}{100}$ ccup d by spheres in unit cell × 100

- The magnitude of <u>ing</u> en in y gives a measure of how tightly particles are packed together.
- > Packing efficient v in diverse it cells:

	Simple cubic unit cell	Body-centred cubic unit cell (bcc)	Face-centred cubic unit cell (fcc) or cubic close packing (ccp)	
onit ce diagram	I date			
Total number of spheres per unit cell	1	2	4	
Relation between a (edge	2	12	a	
length of unit cell) and r	$r = \frac{a}{2}$	$r = \frac{\sqrt{3}}{4}a$	$r = \frac{a}{2\sqrt{2}}$	
(radius of sphere)	2	4		

Challenger Chemistry Vol-II (Med. and Engg.)



Volume of one sphere	$\frac{4}{3}\pi \times \left(\frac{a}{2}\right)^3 = \frac{\pi a^3}{6}$	$\frac{4}{3}\pi \times \left(\frac{\sqrt{3}}{4}a\right)^3 = \frac{\sqrt{3}\pi a^3}{16}$	$\frac{4}{3}\pi \times \left(\frac{a}{2\sqrt{2}}\right)^3 = \frac{\pi a^3}{12\sqrt{2}}$
Total volume of spheres = Number of spheres per unit cell × volume of sphere	$1 \times \frac{\pi a^3}{6} = \frac{\pi a^3}{6}$	$2\times\frac{\sqrt{3}\pia^3}{16}=\frac{\sqrt{3}\pi a^3}{8}$	$4 \times \frac{\pi a^3}{12\sqrt{2}} = \frac{\pi a^3}{3\sqrt{2}}$
Packing efficiency = $\frac{\text{Total volume of spheres}}{\text{Volume of unit cell}} \times 100$	$\frac{\pi a^3 / 6}{a^3} \times 100 = 52.4 \%$	$\frac{\sqrt{3}\pi a^3}{8 a^3} \times 100 = 68\%$	$\frac{\pi a^3}{3\sqrt{2} a^3} \times 100 74.$
Empty space	47.6%	32%	<u> </u>
Coordination number of sphere	6 : four in the same layer, one directly above and one directly below	8 : four in the layer below and one in the laye above	12 six its c n layer the ab re and uree ow

Smart tip - 1

From the above derivations, we can deduce the following relations between $e_{x} = e_{x}$ length (a) of the unit cell and radius of particle, volume of one particle and total volume occ p_{x} and p_{x} is in a unit cell:

	Simple cubic unit cell		bcc unit cell		fcc/ccp unit cell
;	Radius of particle (r)	.:	Radius of .rticle (r)		Radius of particle (r)
1.	= 0.5000 a	11.	= 0.330 a		= 0.3535 a
	Volume of one particle		Volume on ne particle		Volume of one particle
1V.	$= 0.524 a^3$	v.	= 0.3 ³	VI.	$= 0.185 a^3$
	Total volume occupied		Total volume occupied by		Total volume occupied by
vii.	by particles in unit cell	viii.	^{ci} cles in unit cell	ix.	particles in unit cell
	$= 0.524 a^3$		$= 0.68 a^3$		$= 0.74 a^3$

Relationship between the neare. neig. nur 'stance (D) and the edge length (a) of a cubic unit cell:

No.	Type of un [;] cen	Relation between D and a	
i.	Simple cubic	$D = edge \ length = a$	
ii.	Body-centro ¹ cubic	$D = \frac{1}{2} \times body \ diagonal = \frac{1}{2} \times \sqrt{3} \ a$	
iii.	Face d cubic	D = $\frac{1}{2}$ × face diagonal = $\frac{1}{2}$ × $\sqrt{2}$ a = $\frac{a}{\sqrt{2}}$	

Note: Paring officiency in hexagonal close packing (hcp) arrangement:

i. A http://h. Il contains 12 corner spheres, 2 face-centred spheres and 3 body-centred spheres.

Num pr of pheres per unit cell =
$$\left(12 \times \frac{1}{6}\right) + \left(2 \times \frac{1}{2}\right) + 3 = 2 + 1 + 3 = 6$$

Le 'r' represent the radius of the sphere
leight of unit cell = 4r. $\sqrt{\frac{2}{3}}$

Base area of regular hexagon = $6 \times \frac{\sqrt{3}}{4} (2r)^2 = 6 \times \sqrt{3} r^2$

iii. Volume of unit cell = Base area × height (h) =
$$6\sqrt{3} r^2 \times 4r$$
. $\sqrt{\frac{2}{3}}$

 $= 24 \sqrt{2} r^3$





in a r^{-it} ceh.

Simp' cub' un. ce'	bcc unit cell	fcc unit cell
• = a	$D = \frac{\sqrt{3}a}{2}$	$D = \frac{a}{\sqrt{2}}$

6. D sity of unit cell (d):

 $d = \frac{Mass of unit cell}{Volume of unit cell} = \frac{Z \times M}{a^3 \times N_A} g \text{ cm}^{-3}$

where, a is the edge length of unit cell in cm Z is the number of atoms per unit cell M is the molar mass (g/mol)

N_A is Avogadro number $(6.022 \times 10^{23} \text{ mol}^{-1})$ For fcc, Z = 4, for bcc, Z = 2 and for simple cubic, Z = 1

- (B) (ii), (iii), (iv) and (vi)
- (C) (ii), (iii), (v) and (vi)
- $(D) \quad (i), (ii), (iii), (v) \text{ and } (vi)$

1.1 CLASSIFICATION OF SOLIDS

- 1. Which of the following is NOT true about crystalline solids?
 - (A) They have long range order.
 - (B) They have sharp and characteristic melting points.
 - (C) Their measured electrical conductance changes with the change in direction of measurement.
 - (D) They are also known as super cooled liquids.

4. Which is the INCORRECT statement?

[NEET (UG) 2017]

- (A) Density decreases in case of crystals with Schottky's defect.
- (B) NaCl(s) is insulator, silicon is semiconductor, silver is conductor, quartz is piezoelectric crystal.
- (C) Frenkel defect is favoured in those ionic compounds in which sizes of cation and anions are almost equal.
- (D) Fe_{0.98}O has stoichiometric metal deficiency defect.
- 5. For a compound the expected structure was fcc lattice, in which 'A' occupies all corner positions and 'B' occupies all face center positions. The molecular formula of such a compound must be AB₃. However, the formula is found to be A_2B_5 . This is because _____.
 - (A) One atom of A is missing in the lattice
 - (B) One atom of B is missing in the lattice
 - (C) One atom of A is replaced with one atom of B in the lattice
 - (D) One atom of B is replaced with one atom of A in the lattice

Practice Problems

1.1 CLASSIFICATION OF SOLIDS

- 1. Which of the following is TRUE above and quartz glass?
 - (A) Quartz is an amorphous . 'id wi 'e , aartz glass is a crystalline solid
 - (B) Both quartz and quartz lass are amorphous solids.
 - (C) Both quartz a quartz glass are crystalline solids.
 - (D) Quartz is a cry, lline the while quartz glass is an morph, s solu

1.2 CLASSIC CAT, N OF CRYSTALLINE SOLIDS

- 1. '2 is insult or as a solid but conducts e. etri .cy is fused state. 'X' is hard and brittl in ne are. Identify 'X'. (B) Calcium fluoride
 - (C) Diamond
- (B) Calcium fluoride(D) Sulphur dioxide
- 2. Atch the following solids in column I with the major bonding/attractive force between the constituent particles in column II.

	Column I		Column II
i.	Dry ice	a.	Covalent bonding
ii.	Magnesium	b.	London forces
iii.	Graphite	c.	Electrostatic forces
iv.	Common salt	d.	Metallic bonding

- (A) i-a, ii-c, iii-b, iv-d
- (B) i-b, ii-d, iii-a, iv-c
- (C) i-a, ii-d, iii-b, iv-c
- (D) i-c, ii-d, iii-a, iv-b

1.4 BRAGG'S LAW AND ITS APPLICATIONS

- 1. At what value of angle of incidence would the second order diffraction occur, when a r has
 - $\lambda = d = 160 \text{ pm}?$ (A) 30° (B) 45° (C) 60° (D)

1.5 SEVEN CRYSTAL SYS EN .

- 1. A dice represents _____ crys. .em. (A) cubic (. tetragonal (C) orthorho .oic (D) .nonoclinic
- 2. For which on the folloting pairs of crystal systems that the hip $a \neq b \neq c$ is CORRECT?
 - (A) Hexage lan tetragonal
 - (B) Tetragon and rhombohedral
 - (C) thorp nbic and triclinic
 - (D) Monoctinic and cubic
- 3. Matc the following:

		Crystal system		Example
l	i.	Triclinic	a.	TiO ₂
	ii.	Orthorhombic	b.	$K_2Cr_2O_7$
	iii.	Hexagonal	c.	BaSO ₄
	iv.	Tetragonal	d.	ZnO

- (A) i-b, ii-c, iii-d, iv-a
- (B) i c, ii b, iii a, iv d
- (C) i-b, ii-a, iii-d, iv-c
- (D) i c, ii d, iii b, iv a

1.7 PACKING IN SOLIDS

- 1. Which of the following is INCORRECT regarding the ABAB type, two-dimensional arrangement?
 - (A) The coordination number of each sphere is 6.
 - (B) This arrangement forms hexagonal close packed structure.
 - (C) A regular hexagon is formed when the centres of six neighbouring spheres, surrounding a central sphere, are joined.
 - (D) The spheres of successive layers have horizontal and vertical alignment.
- 2. A sample of metal has 5×10^3 fcc unit cells. Calculate the number of tetrahedral voids present.
 - $\begin{array}{cccc} (A) & 2\times 10^3 & (B) & 5\times 10^3 \\ (C) & 2\times 10^4 & (D) & 4\times 10^4 \end{array}$

Challenger Chemistry Vol-II (Med. and Engg.)



A mixed oxide has oxide ions arranged in ccp 3. array. One-fifth of tetrahedral voids are occupied by X ions, while one-half of the octahedral voids are occupied by Y ions. The formula of this oxide is (A) $X_4Y_5O_{10}$ (B) $X_{8}Y_{5}O_{13}$

 X_4Y_5O (D) $X_{5}Y_{4}O_{10}$ (C)

4. Identify the CORRECT increasing order of coordination number of the cations in the crystals of MgS, MgO and CsCl on the basis of data given below:

Radius in Å: $Mg^{2+} = 0.65$, $Cs^+ = 1.69$,

$$O^{2-} = 1.40, S^{2-} = 1.84, Cl^{-} = 1.81$$

- MgS < MgO < CsCl(A)
- (B) MgO < MgS < CsCl
- CsCl < MgO < MgS(C)
- (D) MgS < CsCl < MgO

1.8 PACKING EFFICIENCY

- 1. Three different metal atoms crystallize in simple cubic, bcc and fcc lattice structures. If the edge (Ī) length is 88 pm for all the three unit cells what is the ratio of the radii r_1 in simple cubic lattice, r_2 in bcc lattice, r_3 in fcc lattice?
 - (A) 1.41 : 1.22 : 1 (B) 1.87 : 2.24 : 1
 - (D) 1.41 : 1 : 1.22 (C) 1.24 : 1.87 : 1
- CsI crystallizes in body-centred cubic lattice. 2. Which of the following expressions is CORRECT for CsI?
 - (A) $r_{Cs^+} + r_{T^-} = 3 \times edge \ lengt^{\downarrow}$
 - (B) $r_{Cs^+} + r_{\Gamma} = \frac{3}{2} \times edge length$
 - (C) $r_{Cs^+} + r_{\Gamma} = \frac{\sqrt{3}}{2} \times edge$ ength (D) $r_{0+} + r_{1-} = \frac{\sqrt{3}}{4}$ dy a.

1.9 CALCUL IN COF DENSITY OF UNIT C. LS

- A ' Jua. 'om c. stallises in a cubic system with 1. a lack; g "ciciency of 74%. If the edge length is 10^{\prime} pm a α the atomic mass is M, the density
 - of th. cell is given by $g \text{ cm}^{-3}$. 1.66 × M $2.40 \times M$ (B) 1 (C) $3.32 \times M$ (D) $6.64 \times M$

 Λ ' crystallizes in fcc lattice. Suppose the atomic radius of 'X' is 130 pm and molar mass is 63.5 g/mol. The volume of its unit cell and

- 3. A metal 'X' has fcc structure with atomic radius 140 pm. If the density is 12.69 g/cm³, metal 'X' is
 - (B) Zn (A) Ag Sn (C) (D) Fe
- 4. An unknown element 'X' crystallizes ir fcc lattice. If radius of the atom is 70.7 pm density is 41.6 g cm⁻³, how many atoms of 'X are contained in 200 g sample of the ele (A) 6.0×10^{23} atoms (B) 1.7×1 r^{24} atom (C) 2.4×10^{24} atoms (D) $3.5 \times r^{25}$ atoms
- Calcium crystallizes in a face centry cuby init 5. cell with a = 0.556 nm. Cal tlate the ensity if it contained 0.2% Sc. " y d is. (A) 1.475 g cm⁻³ (b) g cm⁻³ (c) 1.718 g cm⁻³ (c) 1.718 g cm⁻³ (c) 1.903 g cm⁻³
- AB crystalli in a bc -centred cubic lattice, 6. with unit cell e. \sim length, $\delta . 12 \times 10^{-8}$ cm. If the radius $\frac{1}{100}$ ion $\frac{303}{303}$ pm, radius of B²⁻ ion is

(A)
$$\overline{1.9} \times 10^{-}$$
 cm (B) 400 pm
(C) 1. J^{-8} cm (D) 1100 Å

- 1.11 C ASSIFICATION OF POINT D' FECTS
- 1. Which of the following statements are CORRECT?
 - Frenkel defect is a point defect that do not I. disturb the stoichiometry of the solid.
 - Non-stoichiometric defects are also called II. intrinsic defects.
 - Schottky defect is found in ionic III. compounds with high degree of ionic character.
 - IV. Metal excess defect is a point defect that do not disturb the stoichiometry of the solid.
 - V. Metal deficiency defect imparts colour to the colourless crystal due to formation of F-centres.
 - I and III III and V (A) **(B)**
 - II, IV and V (D) I, III and IV (C)

MISCELLANEOUS

- 1. A halide ion forms a close packed structure. If radius of X^{-} ion is 221 pm, what is the maximum radius of the cation that can just fit into the tetrahedral hole and octahedral hole respectively?
 - (A) 36.5 pm and 73 pm
 - 43.8 pm and 80.7 pm (B)
 - 49.7 pm and 91.5 pm (C)
 - (D) 58.6 pm and 100.4 pm

Chapter 1: Solid State

- 2. Which of the following statements are CORRECT about cubic close packed (ccp) 3-D structure?
 - I. The unit cell edge length is $2\sqrt{2}$ times the radius of the atom.
 - II. The number of octahedral and tetrahedral voids per atom are 1 and 2 respectively.
 - III. The number of the nearest neighbours of an atom present in the topmost layer is 12.
 - IV. The packing efficiency of the arrangement is 74%.
 - (A) I, IV (B) II, IV
 - (C) II, III, IV (D) I, II, IV

Diagram Based Problems

1. The following figure represents a unit cell belonging to crystal system.



- (A) tetragonal(B) cubic(C) triclinic(D) orthorl mbic
- 2. Identify the CORRECT option. with a start to the following unit cell diagram.



	C ·	'dinatı	Total number of
	Ь	nber	atoms per unit cell
(A)		1.	4
3)		6	9
(\mathcal{J})		5	9
(D)		8	2

The unit cell of a metal having atomic radius of r is shown in the given diagram. If edge ingth is a cm, then the total volume occupied by the particles in the unit cell is:

- (A) $0.34 a^3$
- (B) $0.68 a^3$
- (C) $0.74 a^3$
- (D) $0.185 a^3$



4. The following diagram shows the three layers of fcc unit cell. Each sphere represents an atom.



A face diagonal passing thr ugh i cen, of atom 1 will also pass thr ugh ine entre of atoms_____.

(A)	3 and 5	<u>(</u> В)	and 11
(C)	2, 4 and 10	(.	3, 5, 6, 7, 11 and 13

5. Which of the follow. is TRUE about the following crys 'defect?



- (A) Density of the solid decreases.
- (B) Compounds having high coordination number show this defect.
- (C) The substance is not electrically neutral.
- (D) KCl does not exhibit this defect.
- 6. Unit cell structure of a certain compound is shown in the given diagram. The empirical formula of the compound is _____.
 - (A) MX_2 (B) M_2X (C) M_4X O = M O = M O = MO = X
 - (D) MX₄
- 7. Find the INCORRECT equation for the given diagram.
 - (A) Edge length of the unit cell = $\frac{4}{\sqrt{2}}$ r (B) Volume of unit cell = $\frac{32}{\sqrt{2}}$ r³ (C) Volume of four spheres = $\frac{16}{3}$ π r³ (D) Fraction occupied = $\frac{\pi\sqrt{3}}{8}$





How many among the following crystalline solids show the above illustrated metal defect? NaCl, AgCl, KCl, CsCl, KBr, AgBr, AgI, ZnS (A) 2 (B) 4

(C) 5 (D) 6

245 Numerical Value Type Questions

1. A metal crystallizes in face-centred cubic lattice with edge length of 400 pm. If the density of the metal is 8 g cm⁻³, then the number of atoms present in 256 g of the metal sample is $N \times 10^{24}$. Value of N is

[Ans: 2]

2. How many total spheres of constituent particles are present in bcc type of unit cell?

[Ans: 2]

3. A metal sample has 5×10^4 fcc unit cells. The total number of tetrahedral voids preceive 4×10^x . The value of x is:

V .s: 5]

4. If a metal crystallizes in face-c, tred code lattice with metallic radius 25 ym, the number of unit cells in ...00 cm of lattice is 2.8×10^{x} . Value of x is

[Ans: 24]

The edge of unit cell of Xe crystal having fcc structure is 620 pm. The radius of Xe atom is pm.

[Ans: 219.17]

 How many of the following compounds show ferrimagnetism? Fe₃O₄; MgFe₂O₄; CrO₂; ZnFe₂O₄; MnO; H₂C.

[Ans. 3]

7. In a face centred cubic lattice, atom A ccc_{1} is the corner positions and atom B ccc_{1} ipies the face centre positions. If one atom f B is missing from one of the face c_{1} ipon the formula of the compound is $c_{x}B_{y}$ in evaluat of v' is

[Ans: 5]

🦨 Problems 7

5.

- 1. It was observe that in a tain crystal of NaCl, 1.2 % N⁺ nd C. fons were found missing. The edge ength Na is 564 pm. How is the observed densition of NaC
 - (A) Observed density is greater than the valculated density by 0.03 g cm^{-3}
 - (B) Dbserved density is smaller than the calculated density by 0.03 g cm^{-3}
 - C) Observed density is smaller than the calculated density by 0.09 g cm^{-3}
 - (D) Observed density is greater than the calculated density by 0.09 g cm^{-3}
- 2. If the edge length of fcc crystal lattice is 500 pm then what is the diameter of the greatest sphere which can be fitted into interstitial void without distortion of the lattice?

(A) 87 pm(C) 139 pm

(B) 117.6 pm (D) 146.4 pm

Answers to MCQs

~ (m	2 <u>4</u>	Bu	ldir	ıg I	robl	em	S												
1.0:	1.	(C																		
•		(D)	2.	(C)	3.	(A)	4.	(B)	5.	(D)										
1.2:	1.	(B)	2.	(A)	3.	(D)	4.	(C)	5.	(D)										
1	1.	(B)																		
1.5:	1.	(D)	2.	(C)	3.	(C)	4.	(C)												
1.6:	1.	(D)	2.	(A)	3.	(B)														
1.7:	1.	(C)	2.	(D)	3.	(C)	4.	(B)	5.	(C)	6.	(A)	7.	(B)	8.	(B)	9.	(C)	10.	(D)
1.8:	1.	(D)	2.	(A)	3.	(D)	4.	(D)	5.	(B)	6.	(B)	7.	(D)	8.	(B)	9.	(D)		

30

Chapter 1: Solid State

1.9:	1.	(B)	2.	(C)	3.	(B)	4.	(D)	5.	(A)	6.	(C)	7.	(A)	8.	(D)	9.	(C)	
1.11:	1.	(A)	2.	(C)	3.	(C)	4.	(B)	5.	(A)	6.	(B)	7.	(C)	8.	(B)			
1.12:	1.	(B)	2.	(C)															
1.13:	1.	(B)	2.	(D)	3.	(C)	4.	(C)	5.	(B)									
1.14:	1.	(A)	2.	(D)	3.	(B)	4.	(C)	5.	(C)	6.	(A)							
Misc.:	1.	(A)	2.	(B)	3.	(B)	4.	(C)	5.	(B)									$ \land$

	P	rac	tice	Pro	oble	ms					
1.1:		1.	(D)								
1.2:		1.	(B)	2.	(B)						
1.4:		1.	(D)								
1.5:		1.	(A)	2.	(C)	3.	(A)				
1.7:		1.	(D)	2.	(D)	3.	(A)	4.	(A)		
1.8:		1.	(A)	2.	(C)						
1.9:		1.	(D)	2.	(C)	3.	(C)	4.	(C)	5.	(B)
1.11	:	1.	(A)								

MISC.: 1. (C) 2. (D)

1. (A) 2. (D) 3. (B) 4. 5. (D) 6. (B) 7. (D) 8. (C)

🧩 Problems To Ponder

1. (B) 2. (D)

Hints to MCQs

6.



1.1 C' AS, FICA YON OF SOLIDS

ч.

Amo hous solids exhibit isotropy. Among the given on ons, quartz glass is an amorphous sul and thus, it exhibits isotropy.

1.2 C ASSIFICATION OF CRYSTALLINE SOLIDS

- 3. Metals contain free electrons which absorb light at one angle and transmit at a different angle. Hence, metals have lustre.
- 5. Diamond is a covalent or network solid and is a poor conductor of electricity.

- 1.4 BRAGG'S LAW AND ITS APPLICATIONS
- 1. $n = 1, d = 3 \text{ Å}, \theta = 9^{\circ}$ According to the Bragg's equation, $n\lambda = 2d \sin \theta$ $\lambda = 2d \sin \theta = 2 \times 3 \times \sin 9^{\circ}$

$$\lambda = \frac{1}{n} = \frac{1}{1}$$

= 6 × 0.1564 = 0.94 Å

- 1.5 SEVEN CRYSTAL SYSTEMS
- 1. A rhombohedral unit cell has all the sides of equal length.
- 3. The triclinic system has all the three sides different $(a \neq b \neq c)$ and all the three angles different $(\alpha \neq \beta \neq \gamma \neq 90^{\circ})$. Hence, it is the most unsymmetrical crystal system. Example is H₃BO₃.

Chapter 1: Solid State

For bcc. $\sqrt{3} a = 4r$ Hence, $r = \frac{\sqrt{3}}{4} \times 288 \text{ pm}$ Since, there are four metal atoms in one unit cell, the given metal crystallizes in fcc lattice. Using Smart Tip - 1 (iii), 2. r = 0.3535 a Where r = radius of the sphere a = edge length of the unit cell = 361 pm $r = 0.3535 \times 361 = 127.6 \text{ pm} \approx 127 \text{ pm}$ The packing efficiency in bcc unit cell = 68%. The percentage of vacant space of bcc unit cell = 100 - 68 = 32%. packing efficiency in fcc unit cell = 74%packing efficiency in bcc unit cell = 68%*.*.. packing efficiency in sc unit cell = 52.4%Thinking Hatke - Q.6 Among crystal structures, fcc type has the most efficient packing. Hence, only option (B) is valid. 3. For an fcc lattice, the nearest neighbour distance (D) = $\frac{1}{2}$ × face diagonal = $\frac{a}{\sqrt{2}} = \frac{640}{\sqrt{2}} = 452$ mm ÷. For a bcc unit cell, *.*.. $r^+ + r^- = \frac{\sqrt{3}}{2}a$ $a = \frac{275 \times 2}{\sqrt{3}}$ 4. *.*.. $=317.5 \times 10^{-10}$... (since, $r^+ + r^- = 2$ /5 pm) :. 1.9 CALCU TION OF DENSITY OF UNIT CEL S Stry 25 N .ure of lattice Value of Z a and M (given) Use formula: $d = \frac{Z \times M}{a^3 \times N}$ Density (d)

3.

4.

5.

...

6.

8.

9.

1.

For bcc unit cell, Z = 2Edge length, $a = 400 \text{ pm} = 400 \times 10^{-10} \text{ cm}$ Density of unit cell, $d = \frac{Z \times M}{a^3 \times N_A} g cm^{-3}$ $=\frac{2\times100}{(400)^3\times(6.022\times10^{23})\times10^{-30}}=5.189 \text{ g/cm}^3$ For fcc unit cell, Z = 4Edge length = $a = x \text{ Å} = 10^{-8} x \text{ cm}$, $M = 63.5 \text{ g mol}^{-1}$ Density = $\frac{Z M}{a^3 N}$ g cm⁻³ $=\frac{4\times 63.5 \text{ g n}}{(10^{-8} \text{ x cm})} \frac{1}{0.0 \times 1} \frac{1}{\text{mol}^{-1}}$ $=\frac{423}{x^3}gc$ Density of cop, r at T (K, = $\frac{423}{r^3}$ g cm⁻³. **C JUTION** Ensure to construct edge length from Å to cm before s ostituting in the density formula. $-\pi$ Å = 3.14 Å = 3.14 × 10⁻⁸ cm $V = (a)^3 = 3.09 \times 10^{-23} \text{ cm}^3$ M = 128 g/mol $d = \frac{ZM}{V.N_A} = \frac{1 \times 128}{3.09 \times 10^{-23} \times 6.022 \times 10^{23}}$ $d = 6.9 \text{ g/cm}^3$ For bcc structure, Z = 2Density of unit cell, $d = \frac{Z \times M}{a^3 \times N}gcm^{-3}$ $a = \left(\frac{Z \times M}{d \times N}\right)^{\overline{3}}$ $\therefore \qquad a = \left(\frac{2 \times 6.94 \text{ g mol}^{-1}}{0.530 \text{ g cm}^{-3} \times 6.02 \times 10^{23} \text{ mol}^{-1}}\right)^{\frac{1}{3}}$ = $(43.5 \times 10^{-24})^{\frac{1}{3}} = 3.517 \times 10^{-8} \text{ cm}$ $= 351.7 \text{ pm} \approx 352 \text{ pm}$ Thinking Hatke - Q.4 We know that $\sqrt[3]{27} = 3$ and $\sqrt[3]{64} = 4$. Therefore, $\sqrt[3]{43.5 \times 10^{-24}}$ will lie between 3×10^{-8} and 4×10^{-8} (i.e., between 300 pm and 400 pm). So, only option (D) is valid.

33

2. 12 atoms are present at 12 corners. Each one contributes $\frac{1}{6}$ to each unit cell.

2 atoms are present at each face. Each one contributes $\frac{1}{2}$ to each unit cell.

3 atoms are completely enclosed within the unit cell.

$$\therefore \qquad 12 \times \frac{1}{6} + 2 \times \frac{1}{2} + 3 = 2 + 1 + 3 = 6$$

3. For fcc lattice,

Density = $\frac{Z \times M}{a^3 \times N_A}$ $Z = 4, a = 361 \times 10^{-10} \text{ cm}$ $d = \frac{4 \times 63.5}{(361 \times 10^{-10})^3 \times 6.022 \times 10^{23}} = 8.96 \text{ g cm}^{-3}$

The observed density of crystal is 9.2 g cm⁻³ which is higher than the calculated density. Hence, crystal has interstitial defect.

Practice Problems

1.2 CLASSIFICATION OF CRYSTALLINE SOLIDS

- 1. 'X' is calcium fluoride (CaF₂) which is an ionic solid. It is an insulator in solid state but conducts electricity in its fused state. ' 1s a. hard and brittle in nature.
- 1.4 BRAGG'S LAW , 'D ITF APPLICATIONS
- 1. According to Bragg's law $n\lambda = 2 c$ in θ Given: n = 2, d = 160 pm, = 160 g n $2 \times 160 = 2 \times 160$... $\sin \theta = 1$ $\therefore \quad \theta = 90^{\circ}$

1.7 PACKIN IN SO. DS

2. In the universe of the number of tetrahedral voids is e tail to two the number of atoms per unit cell. The total method of atoms in an fact unit cell = 4
So, to the of tetrahedral voids per unit cell = 4
Therefore, 5 × 10³ unit cells have 8 × 5 × 10³
total total voids
3. Number of oxide ions in ccp array, n = 4
Number of X ions occupying tetrahedral voids
= 1/5 × 2n = 1/5 × 2 × 2 = 8/5

Number of Y ions occupying octahedral

voids
$$= \frac{1}{2} \times n = \frac{1}{2} \times 4 = 2$$

Ratio of X : Y : O

$$=\frac{8}{5}:2:4=8:10:20=4:5:10$$

 \therefore Formula of the compound is X₄Y₅O₁₀.

4. From radius ratio rule:

For MgS,
$$\frac{r_{Mg^{2+}}}{r_{S^{2-}}} = \frac{0.65}{1.84} = 0.353$$

 \Rightarrow tetrahedral structure with coordinatior number of cation = 4.

For MgO,
$$\frac{r_{Mg^{2+}}}{r_{O^{2-}}} = \frac{0.65}{1.40} = 0.464$$

 \Rightarrow octahedral structure with pord' .atic number of cation = 0

For CsCl,
$$\frac{r_{Cs^+}}{r_{Cl^-}} = \frac{1.69}{1.01} = .034$$

 \Rightarrow Cubic structure with. Pordination number of cation = 8.

1.8 PAC LINE THE MENCY

Usin, Smart T) - 1 (i), Radius Sator forming simple cubic lattice $(r_1) = 0.5\%00$ a Usin, Smart Tip - 1 (ii), Radi 3 of atom forming bcc lattice ($r_2 = 0.4330$ a Using Smart Tip - 1 (iii), Radius of atom forming fcc lattice $(r_3) = 0.3535$ a Ratio = $r_1 : r_2 : r_3 = 0.5000 : 0.4330 : 0.3535$ $= \frac{0.5000}{0.3535} : \frac{0.4330}{0.3535} : \frac{0.3535}{0.3535}$ = 1.41 : 1.22 : 1

💑 Thinking Hatke - Q.1

Since edge length (a) is same, the relation between r_1 (sc), r_2 (bcc) and r_3 (fcc) lattice will be: $r_1 > r_2 > r_3$ Therefore, only option (A) is valid.

2. For a body-centred cubic lattice of CsI with edge length 'a', the length of body Γ diagonal = $\sqrt{3}$ a. But the length of the body diagonal is also equal to $2(r_{cs^+} + r_{\Gamma})$ Γ $\therefore 2(r_{a^+} + r_{\Gamma}) = \sqrt{3}$ a

$$2\left(r_{Cs^{+}} + r_{\Gamma}\right) = \sqrt{3} a$$

or $r_{Cs^{+}} + r_{\Gamma} = \frac{\sqrt{3}}{2}a$



Body-centred unit cell of CsI crystal

8. Diagram shown is that of Schottky defect. Among the given options, NaCl, KCl, CsCl, KBr and AgBr show Schottky defect.



Numerical Value Type Questions

1. For fcc unit cell, Z = 4.

Number of particles in 'x' $g = \frac{xZ}{dc^3}$

Number of atoms in 256 g

$$=\frac{256\times4}{8\times(400\times10^{-10})^3}=2\times10^2$$

- \therefore Value of N = 2
- 3. In fcc unit cell, the number of tetrahedral voids is equal to twice the number of atoms per unit cell.
 - The number of atoms in fcc unit cell = 4
- \therefore No. of tetrahedral voids per unit cell = 8
- $\therefore 5 \times 10^4 \text{ unit cells have } 8 \times 5 \times 10^4 \\ = 4 \times 10^5 \text{ tetrahedral voids} \\ \text{Therefore, value of } x \text{ is } 5.$
- 4. For fcc unit cell, $r = \frac{a}{2\sqrt{2}}$

$$\therefore \qquad \text{Edge length (a)} = 2\sqrt{2} \times r = 2\sqrt{2} \times 25 \,\text{pm}$$

Number of unit cells in volume (V) of metal = $\frac{V}{a^3}$

:. Number of unit cells in 1.00 cm⁻ met, = $\frac{1.00}{(2\sqrt{2} \times 25 \times 10^{-10})^3} = \frac{1.00 \times 10^{30}}{(\sqrt{2} \times 50)^5}$

$$= \frac{100 \times 100 \times 100 \times 10^{24}}{(\sqrt{2})^3 \times 50 \times 50^{-5}0} = \frac{2}{\sqrt{2}} \times \frac{2 \times 10^2}{\sqrt{2}}$$
$$= 2.8 \times 10^{24}$$
Therefore the of $x = 24$

- 5. The t of u. cell is fcc. U ng S t Tip 1 (iii), r 0.? 35 ι When r = t dius of the sphere
 - where T = 0 drug of the sphere
 - = e. cngth of the unit cell = 620 pm
 - $r = 0.3535 \times 620 = 219.17 \text{ pm}$
- 6.

Magnetic property
Ferrimagnetic
Ferrimagnetic
Ferromagnetic
Ferrimagnetic
Antiferromagnetic
Diamagnetic

7	•		
			1.00

Atom/ion	Location	Contribution
		to a unit cell
А	Corners of cube	$\frac{1}{8} \times 8 = 1$
В	Centres of 5 faces	$\frac{1}{2} \times 5 = 5/2$
	(since one atom is	
	missing)	
Ratio	A : B = 1 : $5/2 = 2$:	5
Formula	A ₂ B ₅	

Therefore, value of y is 5.

Problems To Ponde

Number of formula . 's in . nit ce' of NaCl 1. = 4Number of form ' nits n. rin per unit cell $= 4 \times \frac{1.2}{100} = 0^{3}$ Therefore nume of formula units in a unit cell of N? 1 hav. det = 4 - 0.048 = 3.952Obse ved densi $v = d = \frac{ZM}{a^3 \times N_A}$ $= \frac{3.952 \times 58.5}{10^{-22} \times 6.022 \times 10^{23}} = 2.13 \text{ g cm}^{-3}$ C sulated density = d = $\frac{ZM}{a^3 \times N_A}$ $=\frac{4\times58.5}{1.8\times10^{-22}\times6.022\times10^{23}}=2.16 \text{ g cm}^{-3}$ The difference in densities = 2.16 - 2.13 $= 0.03 \text{ g cm}^{-3}$ 2. For fcc unit cell, radius of atom (r) $=\frac{a}{2\sqrt{2}}=\frac{500}{2\times 1.414}=176.8 \text{ pm}$

> As octahedral void is bigger in size than tetrahedral void, the greatest sphere will fit into octahedral void.

Radius of octahedral void

- $= 0.414 \times \text{radius of the atom}$
- $= 0.414 \times 176.8 = 73.2 \text{ pm}$
- \therefore Diameter of the greatest sphere fitting into the void = 2 × 73.2 = 146.4 pm



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